TOSHIBA Transistor Silicon NPN Epitaxial Planar Type (PCT process)

# 2SC2669

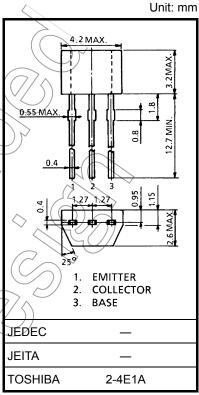
### **High Frequency Amplifier Applications**

- High power gain:  $G_{pe} = 30 dB \text{ (typ.) (f = 10.7 MHz)}$
- Recommended for FM IF, OSC stage and AM CONV, IF stage.

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	35	$\mathcal{M}($
Collector-emitter voltage	V <sub>CEO</sub>	30	V
Emitter-base voltage	V <sub>EBO</sub>	4	$(\sqrt{y})$
Collector current	Ic	50	mA
Base current	ΙΒ	10	mΑ
Collector power dissipation	PC	200	> mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Weight: 0.13 g (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Denating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		Тур.	Max	Unit
Collector cut-off current	ICBO	V <sub>CB</sub> = 35 V, I <sub>E</sub> = 0		_	0.1	μА
Emitter cut-off current	IEBO	V <sub>EB</sub> = 4 V, I <sub>C</sub> = 0	_	_	1.0	μА
DC-current gain	h <sub>FE</sub> (Note)	V <sub>CE</sub> = 12 V, I <sub>C</sub> = 2 mA	40	_	240	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1 mA	_	_	0.4	V
Base-emitter voltage	V <sub>BE</sub>	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1 mA	_	_	1.0	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 1 mA	100	_	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	2.0	3.2	pF
Collector-base time constant	C <sub>c</sub> .r <sub>bb</sub> ,	$V_{CE} = 10 \text{ V}, I_{E} = -1 \text{ mA}, f = 30 \text{ MHz}$	_	_	50	ps
Power gain	G <sub>pe</sub>	$V_{CC} = 6 \text{ V, I}_{E} = -1 \text{ mA, f} = 10.7 \text{ MHz}$ (Figure 1)	27	30	33	dB

Note:  $h_{FE}$  classification R: 40~80, O: 70~140, Y: 120~240

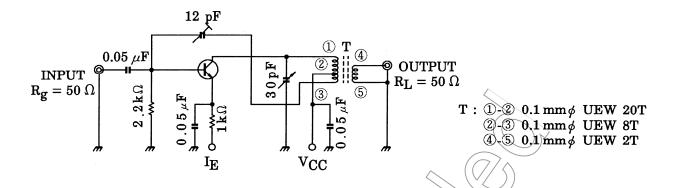


Figure 1 Gpe Test Circuit

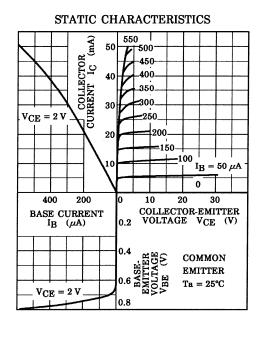
# Y Parameters (typ.)

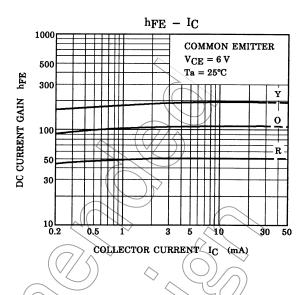
(1) (common emitter f = 455 kHz, Ta = 25°C)

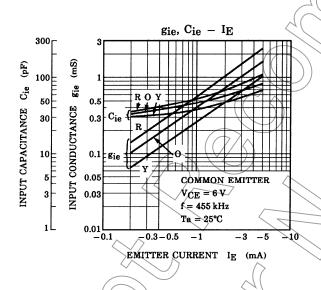
Characteristics	Symbol	2SC2669-R	2SC2669-0	2SC2669-Y	Unit
Collector-emitter voltage	V <sub>CE</sub>	6	6	)) 6	V
Emitter current	ΙE	-1	(-17/	-1	mA
Input conductance	gie	0.58	0.41	0.26	mS
Input capacitance	C <sub>ie</sub>	53	46	38	pF
Output conductance	9oe	1.9	2.7	4.8	μS
Output capacitance	Coe	2.6	2.8	3.6	pF
Forward transfer admittance	yfe	38	38	38	mS
Phase angle of forward transfer admittance	θfe	-0.79	-0.83	-0.92	o
Reverse transfer admittance	// )ly <sub>re</sub> l	5.7	5.7	6.2	μS
Phase angle of reverse transfer admittance	θ <sub>re</sub>	90	-90	-90	0

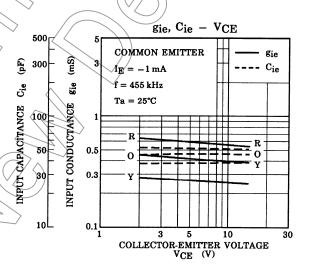
(2) (common emitter f = 10.7 MHz,  $Ta = 25^{\circ}\text{C}$ )

Characteristics	Symbol	2SC2669-R	2SC2669-O	2SC2669-Y	Unit
Collector-emitter voltage	VCE	6	6	6	V
Emitter current	Æ	-1	-1	-1	mA
Input conductance	gie	1.04	0.85	0.65	mS
Input capacitance	Cie	49	43	36	pF
Output conductance	- Goe	10	15	28	μS
Output capacitance	C <sub>oe</sub>	2.7	2.9	3.6	pF
Forward transfer admittance	y <sub>fe</sub>	37	37	37	mS
Phase angle of forward transfer admittance	$\theta_{\sf fe}$	-9.6	-10.4	-11.5	o
Reverse transfer admittance	y <sub>re</sub>	120	120	140	μS
Phase angle of reverse transfer admittance	$\theta_{\sf re}$	-90	-90	-90	٥

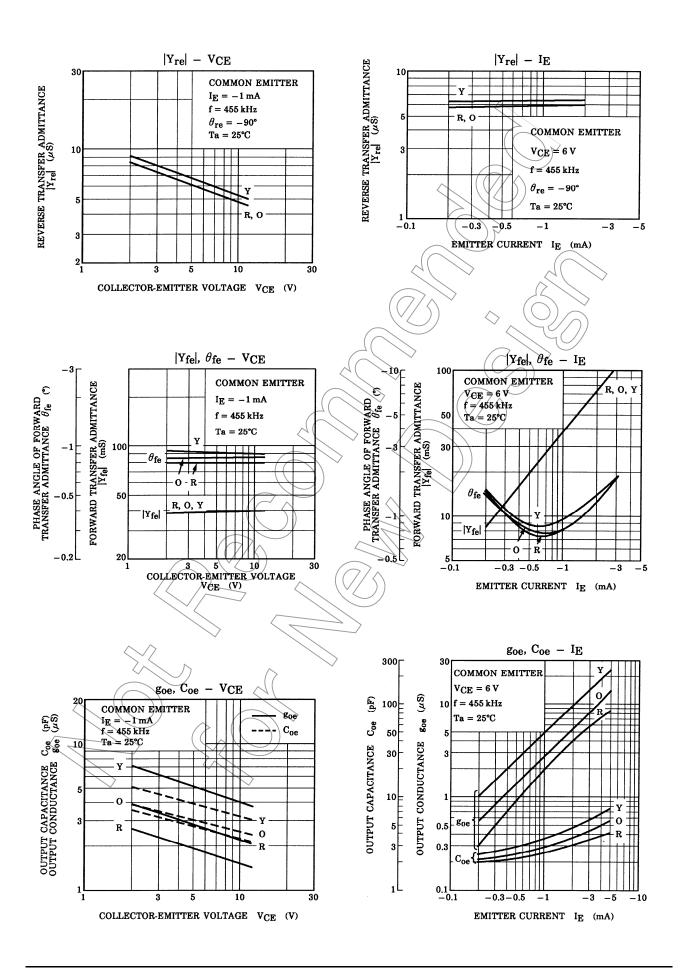


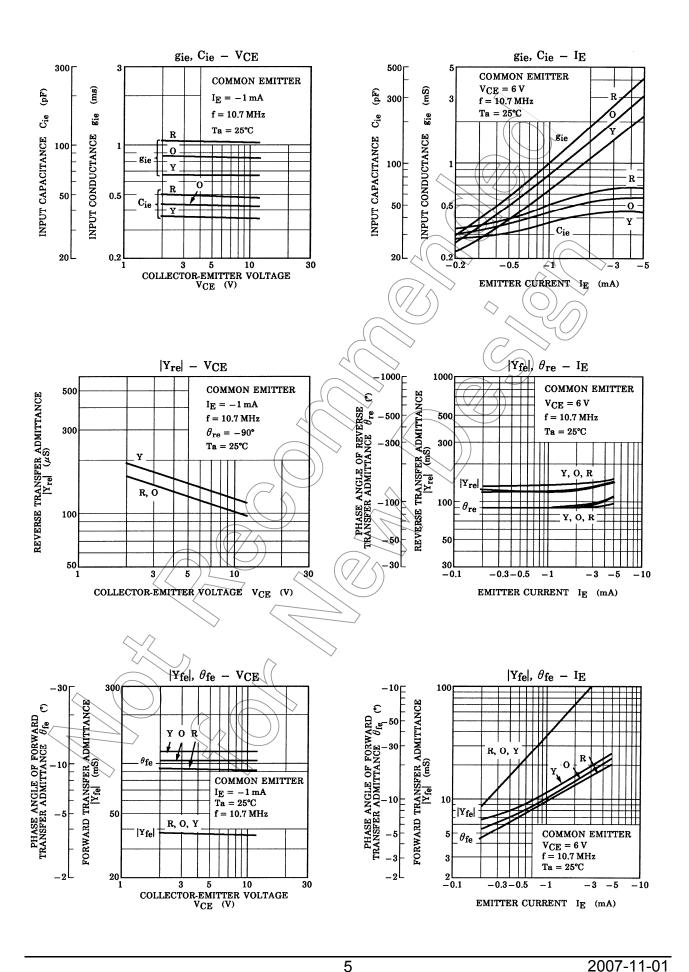


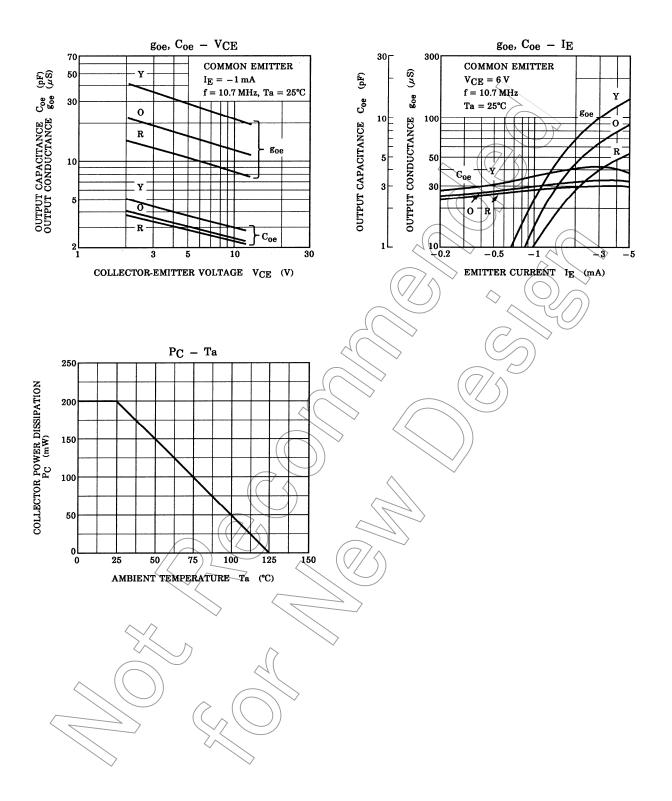




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